Monolithic Amplifier

PMA-545G2+

1.1 to 1.6 GHz 50Ω

3mm x 3mm MCLP Pkg

The Big Deal

- High Gain, 30 dB
- Low Noise Figure, 1.0 dB
- High IP3, 34 dBm

Product Overview

Mini-Circuits PMA-545G2+ is a E-PHEMT based Low Noise MMIC Amplifier operating from 1.2 to 1.6 GHz with a unique combination of low noise and high Gain making this amplifier ideal for sensitive receiver applications. This design operates on a single +5V supply and is internally matched to 50 Ohms.

Key Features

| | Feature | Advantages |
|--------------------|------------------------|---|
| High Gain | 30 dB | Incorporating multiple stages of amplification, the PMA-545G2+ provides high gain reducing cost and PCB board space. |
| Ultra Low Noise: | 1.0 dB NF at 1.4 GHz | Excellent Noise Figure, measured in a 50 Ohm environment – without any external matching. When combined with high gain of this design, it suppresses second stage NF contribution. |
| High IP3: | +34 dBm IP3 at 1.4 GHz | Combining Low Noise and High IP3 makes this MMIC amplifier ideal for Low Noise Receiver Front End (RFE) giving the user advantages at both ends of the dynamic range: sensitivity & two-tone IM dynamic range |
| Output Power: | +22 dBm at 1.4 GHz | The PMA-545G2+ maintains consistent output power capability over the full operating temperature range making it ideal to be used in remote applications such as LNB's as the L Band driver stage |
| Broad Band: | 1.2 to 1.6 GHz | Covering GPS, INMARSAT, Radar |
| Internally Matched | | No external matching elements required to achieve the advertized noise and output power over the full band |
| MCLP Package | | Low Inductance, repeatable transitions, excellent thermal pad |
| Max Input Power | +25 dBm | Ruggedized design operates up to input powers often seen at Receiver inputs. Eliminating need for an external limiter. |
| High Reliability | | Low, small signal operating current of 160 mA nominal maintains junction temperatures typically below 130°C at 85°C ground lead temperature |

Notes
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Monolithic Amplifier

1.1-1.6 GHz

Product Features

- High Gain, 30.4 dB typ. at 1.4 GHz
- Ultra Low Noise Figure, 1.0 dB typ. at 1.4 GHz
- High IP3, 34 dBm typ. 1.4 GHz
- Output Power, up to +22dBm typ. at 1.4 GHz
- Single Positive Supply Voltage, 5V
- Micro-miniature size 3mm x 3mm
- Aqueous washable
- Protected by U.S. patent no. 8,803,612



CASE STYLE: DQ849

+RoHS Compliant The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

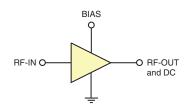
Typical Applications

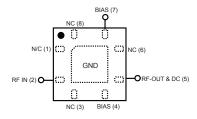
- Airborne Radar
- GPS
- INMARSAT

General Description

PMA-545G2+ is a high dynamic range, low noise, high IP3, high output power, monolithic amplifier. Manufactured using E-PHEMT* technology enables it to work with a single positive supply voltage. Unconditionally stable over the operating frequency.

simplified schematic and pad description





| Function | Pad Number | Description (See Application Circuit, Fig. 2) |
|-------------|----------------------------|---|
| RF-IN | 2 | RF input pad (connected to RF-IN via C1) |
| RF-OUT & DC | 5 | RF output pad (connected to RF-OUT via blocking external cap C2, and Supply voltage Vs via RF Choke L2) |
| BIAS | 4 & 7 | Bias pad 4 connects to Vs via L1 & pad 7 connects to Vs |
| GND | paddle in center of bottom | Connected to ground |
| NOT USED | 1,3,6,8 | No internal connection; recommended use: per PCB Layout PL-346 |

^{*}Enhancement mode Pseudomorphic High Electron Mobility Transistor.

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Electrical Specifications⁽¹⁾ at 25°C, Vd=5V, Zo=50 Ω , (refer to characterization circuit)

| Parameter | Condition (GHz) | Min. | Тур. | Max. | Units |
|--|-----------------|------|--------|------|-------|
| Frequency Range | | 1.1 | | 1.6 | GHz |
| DC Voltage (Vd) | | 4.8 | 5.0 | 5.2 | V |
| DC Current | | | 158 | 186 | mA |
| | 1.1 | | 1.0 | _ | |
| Noise Figure | 1.4 | | 1.0 | 1.4 | dB |
| | 1.6 | | 1.1 | _ | |
| | 1.1 | _ | 31.0 | - | |
| Gain | 1.4 | 27.2 | 30.4 | 33.4 | dB |
| | 1.6 | _ | 29.6 | _ | |
| | 1.1 | | 11.5 | | |
| Input Return Loss | 1.4 | | 13.1 | | dB |
| | 1.6 | | 14.6 | | |
| | 1.1 | | 15.9 | | |
| Output Return Loss | 1.4 | | 14.7 | | dB |
| | 1.6 | | 14.4 | | |
| | 1.1 | | 33.6 | | |
| Output IP3 | 1.4 | | 33.6 | | dBm |
| | 1.6 | | 34.3 | | |
| | 1.1 | | 22.1 | | |
| Output Power @ 1 dB compression (2) | 1.4 | 20.0 | 22.0 | | dBm |
| | 1.6 | | 22.4 | | |
| DC Current Variation vs. Temperature (3) | | | -0.156 | | mA/°C |
| DC Current Variation vs. Voltage | | | 0.027 | | mA/mV |
| Thermal Resistance | | | 48 | | °C/W |

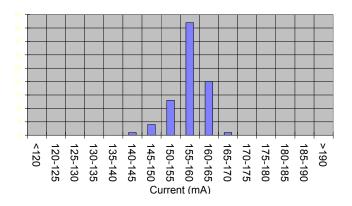
Absolute Maximum Ratings(4)

| Parameter | Ratings | |
|---------------------------|----------------|--|
| Operating Temperature (5) | -40°C to 85°C | |
| Storage Temperature | -65°C to 150°C | |
| Channel Temperature | 150°C | |
| DC Voltage (Pad 4,5,7) | 6V | |
| Power Dissipation | 1.35W | |
| Input Power | 25dBm | |

⁽¹⁾ Measured on Mini-Circuits Characterization test board TB-607-3+

See Characterization Test Circuit (Fig. 1)
(3) (Current at 85°C - Current at -45°C)/130

DC Current Histogram



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⁽⁴⁾ Permanent damage may occur if any of these limits are exceeded.

These maximum ratings are not intended for continuous normal operation.

⁽⁵⁾ Defined with reference to ground pad temperature.

Characterization Test Circuit

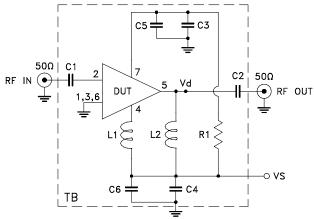


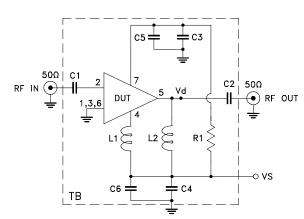
Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization Test Board TB-607-3) Gain, Output power at 1dB compression (P1dB), Output IP3 (OIP3), Noise Figure are measured using Agilent's N5242A PNA-X microwave network analyzer.

Conditions:

- 1. Gain: Pin=-25 dBm
- 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/tone at output.
- 3. Vs adjusted for 5V at device (Vd), compensating loss of bias tee.

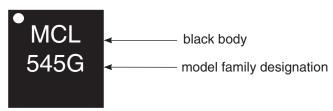
Recommended Application Circuit

(refer to evaluation board for PCB Layout and component values)



| Component | Description |
|----------------|-------------|
| DUT | PMA-545G2+ |
| C1, C2, C5, C6 | 100 pF |
| C3, C4 | 1μF |
| R1 | 0 Ω |
| L1 | 36 nH |
| L2 | 47 nH |

Product Marking



Marking may contain other features or characters for internal lot control

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| Additional Detailed Technical Information additional information is available on our dash board. To access this information click here | | |
|--|--|--|
| | Data Table | |
| Performance Data | Swept Graphs | |
| | S-Parameter (S2P Files) Data Set (.zip file) | |
| Case Style | DQ849 Plastic package, exposed paddle, lead finish: tin-silver over nickel | |
| Tape & Reel | F104 | |
| Standard quantities available on reel | 7" reels with 20, 50, 100, 200, 500,1K or 2K devices | |
| Suggested Layout for PCB Design | PL-346 | |
| Evaluation Board | TB-607-2+ | |
| Environmental Ratings | ENV08T1 | |

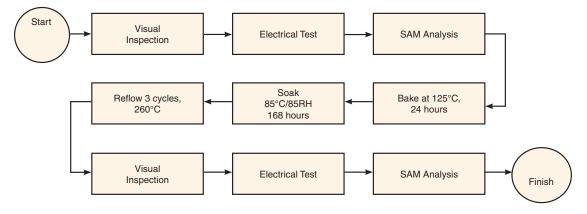
ESD Rating

Human Body Model (HBM): Class 1B (500V to <1000V) in accordance with ANSI/ESD STM 5.1 - 2001 Machine Model (MM): Class M1 (passes 40V) in accordance with ANSI/ESD STM5.2-1999; passes 40V

MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

MSL Test Flow Chart



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